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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/925,952	08/10/2001	Tetsuo Endoh	900-397	5574	
23117 75	90 05/21/2004		EXAM	EXAMINER	
NIXON & VANDERHYE, PC			NGUYEN,	NGUYEN, JOSEPH H	
1100 N GLEBE 8TH FLOOR	ROAD		ART UNIT	PAPER NUMBER	
	VA 22201-4714		2815		
			DATE MAILED: 05/21/200	14	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	09/925,952	ENDOH ET AL.			
Office Action Summary	Examiner	Art Unit			
	Joseph Nguyen	2815			
The MAILING DATE of this communication	appears on the cover sheet	vith the correspondence address			
Period for Reply	TO EVENE	AONTH(S) EPOM			
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, a fix NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by stany reply received by the Office later than three months after the meaned patent term adjustment. See 37 CFR 1.704(b).	PN. R 1.136(a). In no event, however, may reply within the statutory minimum of the country of t	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this communication ABANDONED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 3	31 March 2004.				
2a)☐ This action is FINAL 2b)☒	This action is non-final.	•			
3) Since this application is in condition for all	owance except for formal m	itters, prosecution as to the merits is	S		
closed in accordance with the practice unc	ler Ex parte Quayle, 1935 C	.D. 11, 453 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1,3,5,7-9,11-17,19,29,31-46 and	49-56 is/are pending in the	application.			
4a) Of the above claim(s) is/are with	ndrawn from consideration.				
5) Claim(s) <u>19,37-39 and 55</u> is/are allowed.					
6) Claim(s) 1,3,5,7-9,11-17,29,31-36,39-46,4	<u>19-54 and 56</u> is/are rejected	•	•		
7) Claim(s) is/are objected to.	•				
8) Claim(s) are subject to restriction a	nd/or election requirement.	r'			
Application Papers		•			
O\☐ The specification is objected to by the Exa	miner.				
10) The drawing(s) filed on is/are: a)] accepted or b)☐ objected	to by the Examiner.			
Applicant may not request that any objection t	o the drawing(s) be held in abe	yance. See 37 CFR 1.85(a).			
Parlacement drawing sheet(s) including the c	orrection is required if the draw	ing(s) is objected to. See 37 OFK 1.12 K	(d).		
11) The oath or declaration is objected to by the	he Examiner. Note the attac	hed Office Action or form PTO-152.			
Priority under 35 U.S.C. § 119					
12)⊠ Acknowledgment is made of a claim for fo	reign priority under 35 U.S.	C. § 119(a)-(d) or (f).			
a) ⊠ All b) □ Somé * c) □ None of:	,				
1.⊠ Certified copies of the priority documents have been received.					
2 Certified copies of the priority docu	ments have been received	n Application No			
3. ☐ Copies of the certified copies of the	e priority documents have b	een received in this National Stage			
application from the International E	Bureau (PCT Rule 17.2(a)).	·			
* See the attached detailed Office action for	a list of the certified copies	not received.			
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	and the second of the second o	in the community of the			
Attachment(s)		O			
1) Notice of References Cited (PTO-892)	, — B	ew Summary (PTO-413) No(s)/Mail Date			
2) Notice of Draftsperson's Patent Drawing Review (PTO-9 3) Information Disclosure Statement(s) (PTO-1449 or PTO-	(SB/08) 5) \(\sum_{\text{Notic}} \)	of Informal Patent Application (PTO-152)			
Paper No(s)/Mail Date <u>08/10/2001</u> .	o) Li Other	·			

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DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 3, 5, 7-9, 11-17, 29, 31-36, 39-46, 49-54, 56 are rejected under 35 U.S.C. 102(b) as being anticipated by Burns Jr, et al.

Regarding claim 1, Burns, Jr. et al discloses on figure 10 a semiconductor memory comprising a first conductivity type semiconductor substrate 235; and one or more memory cells comprising an island like semiconductor layer 230, a charge storage layer 265 and a control gate 275, the charge storage layer and the control gate being formed to entirely or partially encircle a sidewall of the island like semiconductor layer, wherein an active region of at least one of said memory cells is electrically insulated from the semiconductor substrate by a second conductivity type impurity diffusion layer 215 formed in the semiconductor substrate or in the island like semiconductor layer and a depletion layer formed at a junction between the second conductivity type impurity diffusion layer 215 and the semiconductor substrate 235 or the island like semiconductor layer 230.

Regarding claims 5, 7-9, 11-17, 29, 31-36, 39-46, 49-54, 56, Burns Jr, et al. discloses on figure 10 all the structures set forth in the claimed invention.

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Allowable Subject Matter

Claims 19, 37-38, 55 are allowed.

Response to Arguments

Applicant's arguments filed on 03/31/2004 have been fully considered but they are not persuasive.

With respect to claims 1, 5, 36, 46, applicant argues that in figure 10, Burns does not disclose or suggest electrically insulating the pillar 230 from the substrate 235 by extending a depletion layer as now recited in the claimed invention. However, on page 16 of the amendment filed on 03/31/2004, applicant admitted that a depletion layer formed on the substrate or the semiconductor layer of a PN junction formed between diffusion layer and the substrate or semiconductor layer by a difference between a potential given to diffusion layer and a potential given to the substrate at times of reading and/ or erasing. However, the way this so-called depletion layer is formed is merely the intended use. One skilled in the art would be able to apply different potentials to diffusion layer and the substrate to obtain the depletion layer in the same manner. Therefore, this does not structurally distinguish Burns from the claimed invention. Further, Burns clearly discloses on figure 10 a pn junction between the second conductivity type diffusion layer 215 in the substrate 235. The substrate 235 can be p doped (col. 8, lines 24-26). This implies that there exists a pn junction therein.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Joseph Nguyen whose telephone number is (571) 272-1734. The examiner can normally be reached on Monday-Friday, 7:30 am- 4:30 pm

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306 for regular communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

JN May 7, 2004

> JEROME JACKSON PRIMARY EXAMINER